



GM-TT62050

DUAL SCR MODULE

Insulated module
 High current, high voltage applications

VOLTAGE UP TO 1600 V
AVERAGE OUTPUT CURRENT 500 A

BLOCKING CHARACTERISTICS

Characteristic		Conditions	Value
V _R RRM	Repetitive peak reverse voltage		1600 V
V _R RSM	Non-repetitive peak reverse voltage		1700 V
V _D DRM	Repetitive peak off-state voltage		1600 V
I _R RRM	Repetitive peak reverse current, max.	V _R , single phase, half wave, T _j = T _j max	100 mA
V _{INS}	RMS insulation voltage	50Hz, 1s, shorted terminals to base	3000 V

ON-STATE CHARACTERISTICS

I _T (AV)	Average on-state current	T _c = 85 °C	500 A
I _T S	Surge current	Non rep. half sine wave, 50 Hz, V _R = 0 V, T _j = T _j max	15 kA
I ² t	I ² t for fusing coordination	Non rep. half sine wave, 50 Hz, V _R = 0 V, T _j = T _j max	1125 kA ² s
V _T (TO)	Threshold voltage	T _j = T _j max	0.9 V
r _T	Forward slope resistance	T _j = T _j max	0.27 mΩ
V _{TM}	Forward voltage, max	Forward current I _F = 1570 A, T _j = 25 °C	1.35 V

THERMAL AND MECHANICAL CHARACTERISTICS

R _{th} (j-c)	Thermal resistance (junction to case)		0.065 °C/W
R _{th} (c-h)	Thermal resistance (case to heatsink)		0.020 °C/W
T _j max	Operating junction temperature		-40 / 125 °C
F	Mounting torque +/- 10%	Module to heatsink	7 N·m
	Mass		1500 g

Ordering information



